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'421 Patent:

Fujitsu Semiconductor Limited, Fujitsu Semiconductor America, Inc., Advanced Micro Devices, Inc., Renesas Electronics Corporation, Renesas Electronics America, Inc., Globalfoundries U.S., Inc., Globalfoundries Dresden Module One LLC & Co. KG, Toshiba America Electronic Components, Inc., Toshiba America Inc., Toshiba America Information Systems, Inc., Toshiba Corporation, and the Gillette Company,

v. Zond, LLC.

 $IPR2014-800^{1}$, $IPR2014-802^{2}$, and $IPR2014-805^{3}$

June 8, 2015

¹ Cases IPR2014-844, IPR2014-991, and IPR2014-1037 are joined with the 800

² Cases IPR2014-848, IPR2014-992, and IPR2014-1071 are joined with the 802

³ Cases IPR2014-851, IPR2014-990, and IPR2014-1069 are joined with the 805

Overview

- Overview of '421 Patent
- Grounds Instituted
- Overview of Prior Art
- Summary of Disputes with Respect to Independent Claims
 - Claim Construction
 - Response to Patent Owner's Arguments
- Summary of Disputes and Responses Related to Dependent Claims

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The '421 Patent

(12) United States Patent Chistyakov

(54)	HIGH DEPOSITION RATE SPUTTERING	
(75)	Tessontae	Raman Chistophov, Andrews MA (US)

(73) Assignee: Zond, Inc., Mansfield, MA (US)

(*) Notice: Subject to any disclaimer, the term of this patent is extended or adjusted under 35 U.S.C. 154(b) by 896 days.

This patent is subject to a terminal dis-

(21) Appl. No.: 11/183,463

(22) Filed: Jul. 18, 2005

Prior Publication Data

US 2005/0252763 A1 Nov. 17, 2005

Related U.S. Application Data

(63) Continuation of application No. 11/091,814, filed on Mar. 28, 2005, now abandoned. (74) Altorway: Agent, or France—Katt Rauschenbach; Rauschenbach Patent Law Group, LLP

(51) Int. Cl. C23C 14/35 (2006.01)

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(10) Patent No.: US 7,811,421 B2 (45) Date of Patent: *Oct, 12, 2010

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Primary Euswiner-Rodney G McDonald Rauschenbach Patent Law Group, LLP

ABSTRACT

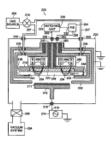
C3C IA35 (2006-01) Methods and apparatus for high-deposition synthesing are described. A synthesing succe includes an arode and a cathesia of Classification Search 2041/92.12; 2042/28.06.

See application file for complete search listory.

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48 Claims, 13 Drawing Sheets



US 7,811,421 B2 (10) Patent No.:

(45) Date of Patent:

*Oct. 12, 2010

(54) HIGH DEPOSITION RATE SPUTTERING

US Patent 7,811,421

The '421 Patent

Anode (238)

Cathode Assembly (216)

Pulsed Power Supply (234)

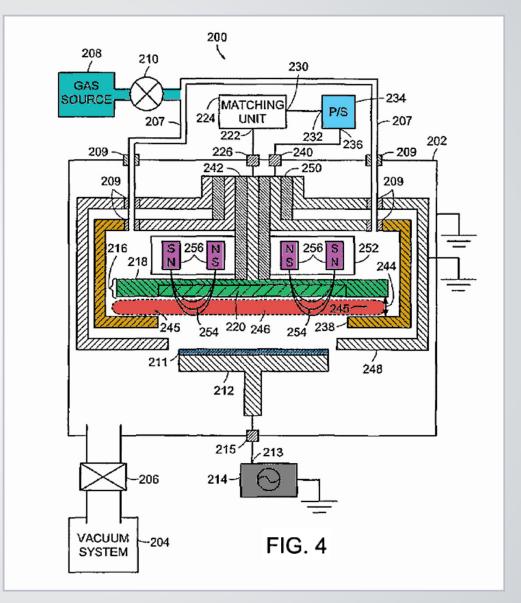
Magnets (256)

Plasma (246)

Feed Gas Source (208)

Substrate (211)

Bias Power Supply (214)



'421 Patent, Fig. 4

Representative Claim

'421 Patent, Claim 1

- 1. A sputtering source comprising:
- a) a cathode assembly comprising a sputtering target that is positioned adjacent to an anode; and
- b) a power supply that generates a voltage pulse between the anode and the cathode assembly that creates a weakly-ionized plasma and then a strongly-ionized plasma from the weakly-ionized plasma without an occurrence of arcing between the anode and the cathode assembly, an amplitude, a duration and a rise time of the voltage pulse being chosen to increase a density of ions in the strongly-ionized plasma.

'421 Patent, Claim 1

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